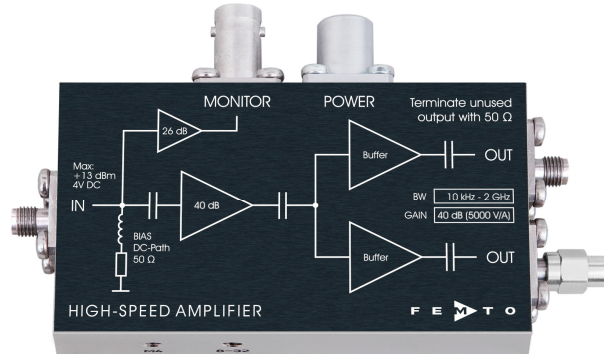



1 GHz High-Speed Amplifier

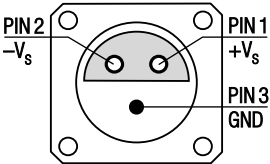


<p>Features</p>	<ul style="list-style-type: none"> • Bandwidth 10 kHz – 1.9 GHz • Exceptional low 10 kHz lower cut-off frequency for optimal pulse processing without shape distortion • Rise time 185 ps • Gain 40 dB • Input return loss 20.8 dB • Integrated bias circuit • Monitor output • Two identical signal outputs
<p>Applications</p>	<ul style="list-style-type: none"> • Preamplifier for ultra-fast detectors (microchannel-plates, photomultipliers, avalanche-photodiodes, PIN-photodiodes etc.) • Oscilloscope and transient-recorder preamplifier • Time-resolved pulse and transient measurements
<p>Block Diagram</p>	<p style="text-align: right; font-size: small;">BS-HSA-Y_23_R01</p>
<p>Intended Use</p>	<p>The HSA-Y-2-40 amplifier is a fixed gain wideband GHz amplifier. It is designed for ultra fast amplification of small voltage and current signals in the frequency range from 10 kHz to 1.9 GHz. Operation is mostly self-explanatory. If in doubt, consult this document or contact support@femto.de.</p> <p>For safe operation, please refer to the damage thresholds specified in the "Absolute Maximum Ratings", "Temperature Range" and "Power Supply" sections of this document.</p>
<p>Application Notes</p>	<p>CAUTION! Do not exceed the maximum allowable input power of +13 dBm (20 mW). If in doubt, use attenuators on the amplifier input.</p> <p>The HSA-Y-2-40 offers two identical RF outputs. For operation it is mandatory that both RF outputs are terminated with 50 Ω loads. If only one output is used, the unused SMA output socket must be terminated with a 50 Ω terminator which is included in delivery.</p>

1 GHz High-Speed Amplifier

Available Accessories	PS-15-25-L 	Power supply Input: AC 100 – 240 V Output: DC ±15 V																																																																																																
Related Models	HSA-Y-1-40 HSA-Y-1-60 HSA-Y-2-20	Gain 40 dB, 10 kHz – 1 GHz, noise figure 1.9 dB Gain 60 dB, 10 kHz – 1.1 GHz, noise figure 1.9 dB Gain 40 dB, 10 kHz – 2 GHz, noise figure 5.2 dB																																																																																																
Specifications	<table border="0"> <tr> <td>Test conditions</td> <td colspan="2">$V_S = \pm 15\text{ V}$, $T_A = 25\text{ }^\circ\text{C}$, system impedance $50\ \Omega$, warm-up 20 minutes (min. 10 minutes recommended)</td> </tr> <tr> <td>Gain</td> <td>Gain</td> <td>40 dB ($\times 100$)</td> </tr> <tr> <td></td> <td>Transimpedance gain</td> <td>5000 V/A ($50\ \Omega$ input impedance $\times 100$ gain)</td> </tr> <tr> <td></td> <td>Gain accuracy</td> <td>$\pm 1\text{ dB}$</td> </tr> <tr> <td></td> <td>Gain drift vs. temperature</td> <td>0.023 dB/$^\circ\text{C}$ typ.</td> </tr> <tr> <td>Frequency Response</td> <td>Lower cut-off frequency (-3 dB)</td> <td>10 kHz</td> </tr> <tr> <td></td> <td>Upper cut-off frequency (-3 dB)</td> <td>1.9 GHz</td> </tr> <tr> <td>Time Response</td> <td>Rise/fall time (10% - 90%)</td> <td>185 ps</td> </tr> <tr> <td></td> <td>Group delay</td> <td>1.0 ns typ.</td> </tr> <tr> <td>Input</td> <td>DC input impedance</td> <td>$50\ \Omega$</td> </tr> <tr> <td></td> <td>RF input impedance</td> <td>$50\ \Omega$</td> </tr> <tr> <td></td> <td>$50\ \Omega$ noise figure</td> <td>4.9 dB (@ $f < 1\text{ GHz}$)</td> </tr> <tr> <td></td> <td>Equ. input noise voltage</td> <td>650 pV/$\sqrt{\text{Hz}}$ (@ $f < 1\text{ GHz}$)</td> </tr> <tr> <td></td> <td>Equ. input noise current</td> <td>13 pA/$\sqrt{\text{Hz}}$ (calculated: 650 pV/$\sqrt{\text{Hz}}$ divided by $50\ \Omega$)</td> </tr> <tr> <td></td> <td>Input reflection S11</td> <td>-21 dB (@ $f < 1.5\text{ GHz}$) -15 dB (@ $f < 3\text{ GHz}$)</td> </tr> <tr> <td>Output</td> <td>Two identical RF outputs:</td> <td></td> </tr> <tr> <td></td> <td>Output peak-peak voltage range</td> <td>1.7 V ($\pm 0.85\text{ V}$) (@ $< 500\text{ MHz}$, for linear amplification)</td> </tr> <tr> <td></td> <td>Output power $P_{1\text{dB}}$</td> <td>+12 dBm (@ $f < 1\text{ GHz}$)</td> </tr> <tr> <td></td> <td>Output impedance</td> <td>$50\ \Omega$ (terminate with $50\ \Omega$ load)</td> </tr> <tr> <td></td> <td>Output reflection S22</td> <td>-10.9 dB (@ $f < 3\text{ GHz}$)</td> </tr> <tr> <td></td> <td>Isolation between outputs</td> <td>20 dB (@ $f < 3\text{ GHz}$)</td> </tr> <tr> <td>Monitor Output</td> <td>Gain</td> <td>26 dB (1 kV/A)</td> </tr> <tr> <td></td> <td>Monitor output impedance</td> <td>$50\ \Omega$ (terminate with $\geq 10\text{ k}\Omega$ load, for best performance)</td> </tr> <tr> <td></td> <td>Lower cut-off frequency</td> <td>DC</td> </tr> <tr> <td></td> <td>Upper cut-off frequency</td> <td>100 kHz</td> </tr> <tr> <td></td> <td>Output voltage</td> <td>$\pm 10\text{ V}$ (@ $10\text{ k}\Omega$ load)</td> </tr> <tr> <td>Power Supply</td> <td>Supply voltage</td> <td>$\pm 15\text{ V}$ ($\pm 14.75\text{ V} \dots \pm 16.5\text{ V}$)</td> </tr> <tr> <td></td> <td>Supply current</td> <td>+185 / -10 mA typ. 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1 GHz High-Speed Amplifier

Connectors	<p>Input SMA jack (female)</p> <p>RF Output 2 × SMA jack (female)</p> <p>Monitor output BNC jack (female)</p> <p>Power supply LEMO® series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)</p> <div style="text-align: center;">  <p style="margin-left: 100px;">PIN 1: +15 V PIN 2: -15 V PIN 3: GND</p> </div>
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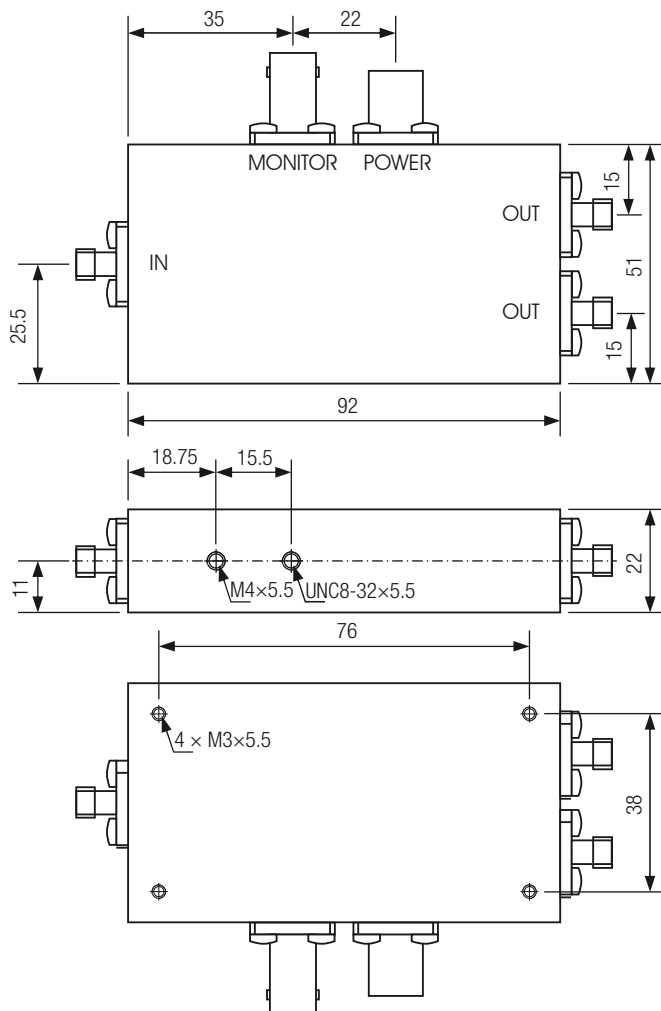
Scope of Delivery	HSA-Y-2-40, 50 Ω SMA terminator, LEMO® 3-pin connector, datasheet, transport package
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Ordering Information	<p>HSA-Y-2-40 High-speed GHz amplifier</p>
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1 GHz High-Speed Amplifier

Dimensions

HSA-Y-2-40



DZ-HSA-Y_23_R01

all dimensions in mm unless otherwise noted

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